

1 *Supplementary Materials*

2 **Geometry Control of Source/Drain Electrodes in**
 3 **Organic Field-Effect Transistors by**
 4 **Electrohydrodynamic Inkjet Printing**

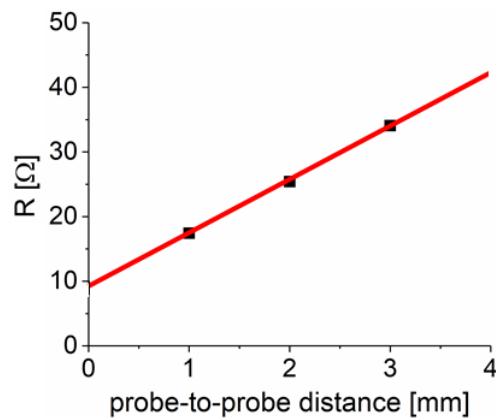
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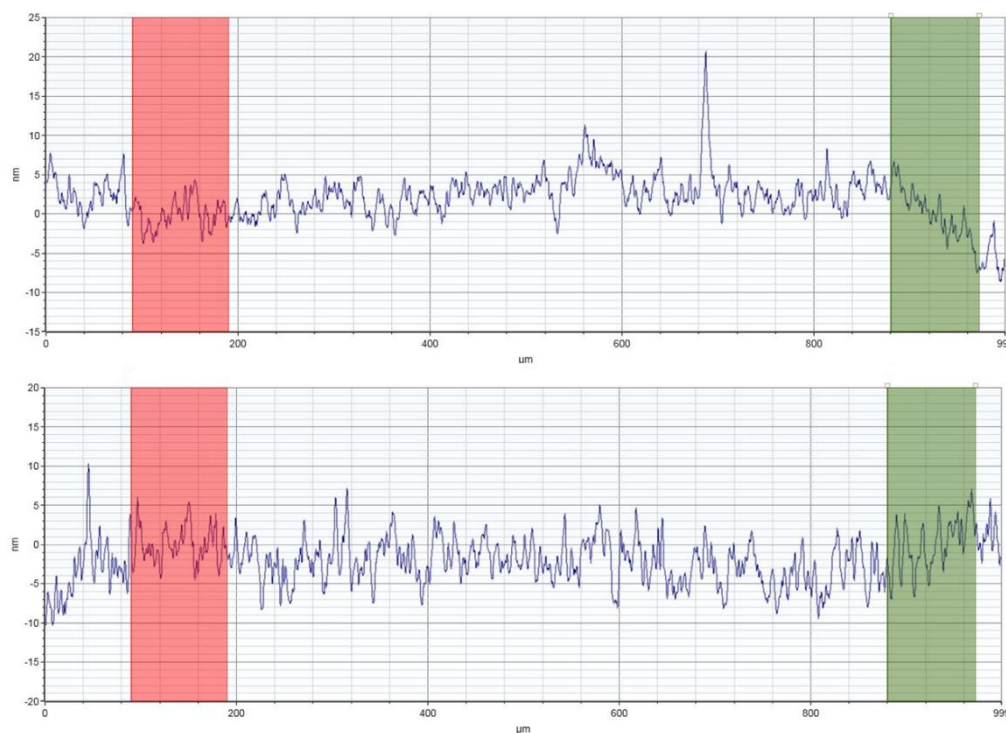
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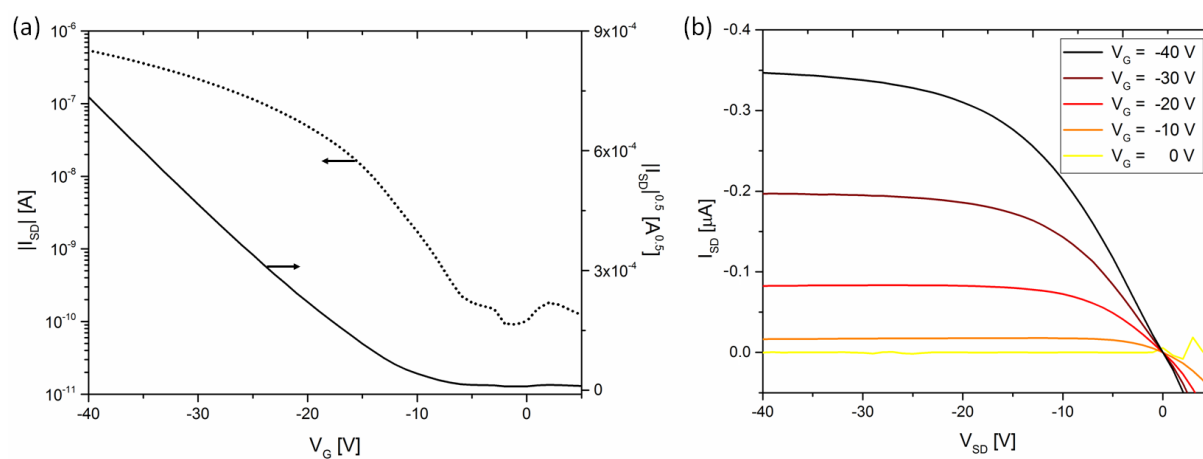
Figure S1. The length-dependent resistance measurements for estimation of the contact resistance.



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Figure S2. Surface profile of single ($n = 1$, top) and double ($n = 2$, bottom) DGP overprints.



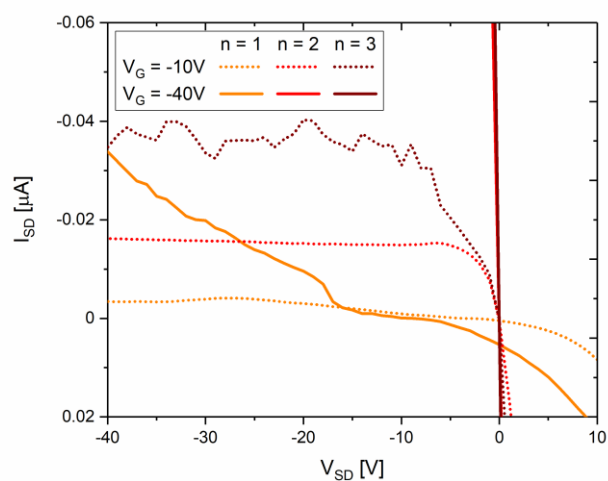
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Figure S3. (a) Transfer and (b) output characteristics of bottom contact/bottom gate OFETs with DPP-DTT as active layer, comprising thermally evaporated Ag electrodes. $V_{SD} = -40$ V for transfer characteristics.



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Figure S4. Output characteristics of bottom contact/bottom gate OFETs with DPP-DTT as active layer, comprising single ($n = 1$), double ($n = 2$) and triple ($n = 3$) overprints as electrodes.



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